

# **High Voltage Switching Diodes**

## **BASH16MX2W**

The BASHxxMX2W Switching Diode is a spin-off of our popular SOT-23 three-leaded device. It is designed for switching applications and is housed in the X2DFNW2 (1.0x0.6mm) surface mount package. This device is ideal for low-power surface mount applications, where board space is at a premium.

#### **Features**

- 175°C T<sub>J(max)</sub> Rated for High Temperature, Mission Critical Applications
- Wettable Flank Package for optimal Automated Optical Inspection (AOI)
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

| Rating   | Symbol                               | Value                                  | Unit |
|--|--------------------------------------|--|------|
| Continuous Reverse Voltage<br>BASH16<br>BASH19<br>BASH20<br>BASH21   | V <sub>R</sub> ,<br>V <sub>RRM</sub> | 100<br>120<br>200<br>250               | Vdc  |
| Continuous Forward Current   | IF                                   | 200                                    | mAdc |
| Repetitive Peak Forward Current (Pulse Wave = 1 sec, Duty Cycle = 66%)   | I <sub>FRM</sub>                     | 500                                    | mA   |
| Non-Repetitive Peak Forward Current (Square Wave, $T_J = 25^{\circ}C$ prior to surge) BASH16 $t = 1 \mu s$ $t = 1 ms$ $t = 1 s$ BASH19/20/21 $t = 1 \mu s$ $t = 1 ms$ $t = 1 ms$ $t = 1 s$ | IFSM                                 | 5.0<br>2.0<br>0.5<br>9.0<br>3.0<br>1.7 | A    |

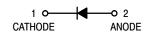
#### THERMAL CHARACTERISTICS

| Characteristic   | Symbol                            | Max            | Unit |
|--|-----------------------------------|----------------|------|
| Total Device Dissipation FR-5 Board T <sub>A</sub> = 25°C (Note 1) | P <sub>D</sub>                    | 300            | mW   |
| Thermal Resistance Junction-to-Ambient (Note 1)                    | $R_{\theta JA}$                   | 400            | °C/W |
| Thermal Resistance Junction-to-Solder Point (Note 1)               | $R_{\theta JSP}$                  | 105            | °C/W |
| Junction and Storage Temperature Range                             | T <sub>J</sub> , T <sub>stg</sub> | −55 to<br>+175 | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Mounted onto a 4 in square FR-4 board 10 mm sq. 1 oz. Cu 0.06" thick single sided. Operating to steady state.

1





MARKING DIAGRAM

X2DFNW2 CASE 711BG



XX = Specific Device Code M = Date Code

#### **ORDERING INFORMATION**

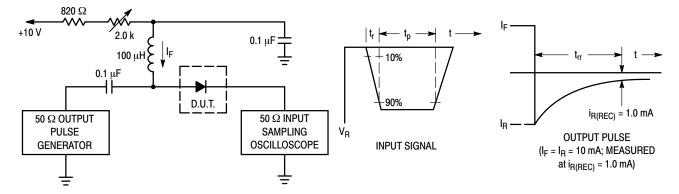
See detailed ordering, marking and shipping information on page 4 of this data sheet.

#### **BASH16MX2W**

**ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Characteristic   |                   | Min | Max  | Unit |
|--|-------------------|-----|------|------|
| OFF CHARACTERISTICS  | •                 |     |      |      |
| Reverse Voltage Leakage Current                                | I <sub>R</sub>    |     |      | μAdc |
| (V <sub>R</sub> = 80 Vdc) BASH16                               |                   | _   | 0.5  | ·    |
| (V <sub>R</sub> = 100 Vdc) BASH19                              |                   | _   | 0.1  |      |
| (V <sub>R</sub> = 150 Vdc) BASH20                              |                   | _   | 0.1  |      |
| (V <sub>R</sub> = 200 Vdc) BASH21                              |                   | _   | 0.1  |      |
| $(V_R = 80 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BASH16     |                   | _   | 50   |      |
| $(V_R = 25 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BASH16     |                   | _   | 30   |      |
| $(V_R = 100 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BASH19    |                   | _   | 100  |      |
| $(V_R = 150 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BASH20    |                   | _   | 100  |      |
| $(V_R = 200 \text{ Vdc}, T_J = 150^{\circ}\text{C})$ BASH21    |                   | -   | 100  |      |
| Reverse Breakdown Voltage (I <sub>BR</sub> = 100 μAdc)         | V <sub>(BR)</sub> |     |      | Vdc  |
| BASH16   | , ,               | 100 | _    |      |
| BASH19   |                   | 120 | _    |      |
| BASH20   |                   | 200 | _    |      |
| BASH21   |                   | 250 | -    |      |
| Forward Voltage  | $V_{F}$           |     |      | Vdc  |
| (I <sub>F</sub> = 100 mAdc)                                    |                   | _   | 1.0  |      |
| (I <sub>F</sub> = 200 mAdc)                                    |                   | -   | 1.25 |      |
| Diode Capacitance (V <sub>R</sub> = 0, f = 1.0 MHz)            | C <sub>D</sub>    | -   | 3.0  | pF   |
| Reverse Recovery Time  | t <sub>rr</sub>   |     |      | ns   |
| $(I_F = I_B = 10 \text{ mAdc}, R_I = 50 \Omega)$ BASH16        |                   | _   | 6.0  |      |
| $(I_F = I_B = 30 \text{ mAdc}, R_L = 100 \Omega)$ BASH19/20/21 |                   | _   | 50   |      |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



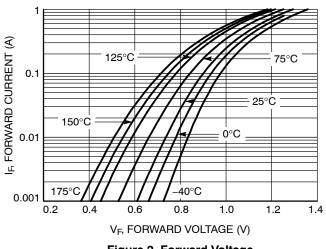
Notes: 1. A 2.0  $k\Omega$  variable resistor adjusted for a Forward Current (IF) of 10 mA.

- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 10 mA.
- 3. t<sub>p</sub> » t<sub>rr</sub>

Figure 1. Recovery Time Equivalent Test Circuit

#### BASH16MX2W

#### **TYPICAL CHARACTERISTICS**



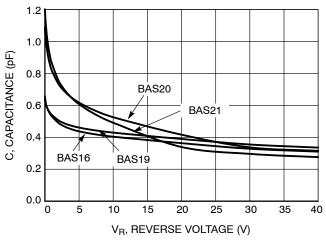
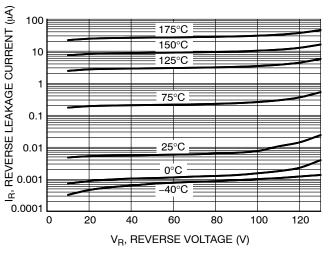


Figure 2. Forward Voltage

Figure 3. Total Capacitance



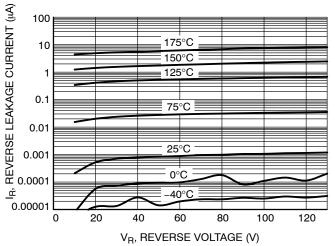
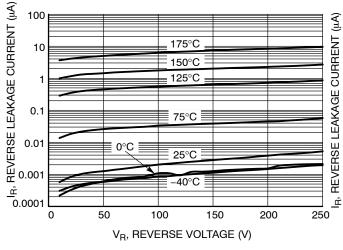


Figure 4. Reverse Current - BASH16

Figure 5. Reverse Current - BASH19





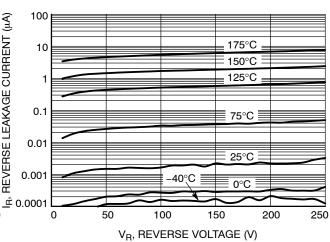


Figure 7. Reverse Current - BASH21

#### BASH16MX2W

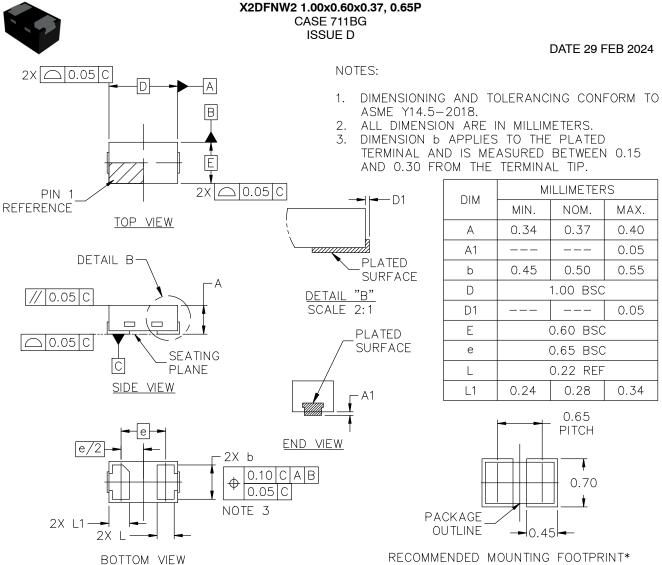
#### **DEVICE ORDERING INFORMATION**

| Device                              | Marking | Package             | Shipping <sup>†</sup> |  |
|-------------------------------------|---------|---------------------|-----------------------|--|
| BASH16MX2WT5G,<br>NSVBASH16MX2WT5G* | MF      | X2DFN2<br>(Pb-Free) |                       |  |
| BASH19MX2WT5G,<br>NSVBASH19MX2WT5G* | ME      |                     | 8000 / Tape & Reel    |  |
| BASH20MX2WT5G,<br>NSVBASH20MX2WT5G* | MG      |                     |                       |  |
| BASH21MX2WT5G,<br>NSVBASH21MX2WT5G* | МН      |                     |                       |  |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP

Capable.





### **GENERIC MARKING DIAGRAM\***

XXM

XX = Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.

| PACKAGE   OUTLINEO.45                     |
|---|
| RECOMMENDED MOUNTING FOOTPRINT*           |
| FOR ADDITIONAL INFORMATION ON OUR PHOFREE |

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|------------------|-------------------------|--|-------------|
| DESCRIPTION:     | X2DFNW2 1.00x0.60x0.37. | 0.65P  | PAGE 1 OF 1 |

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